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(72)Inventor: MATSUSHITA YASUO

NAKAMURA KOSUKE

(54) METHOD FOR FABRICATION OF SEMICONDUCTIVE PRESSURE CONVERTER (57) Abstract:

PURPOSE: To increase adhesive strength and tightness by carrying out adhesion of supporting substrate and pressure sensitive Si element with Au-Si cocrystallizing alloy in high purity H2, Ar, or He atmosphere.

LEGAL STATUS

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